# P54/74FCT139T/AT/CT HIGH-SPEED DUAL 1-OF-4 DECODER

#### **FEATURES**

- Function, Pinout and Drive Compatible with the FCT and F Logic
- FCT-C speed at 5.0ns max. (Com'l) FCT-A speed at 5.9ns max. (Com'l)
- Reduced V<sub>OH</sub> (typically = 3.3V) versions of Equivalent FCT functions
- Edge-rate Control Circuitry for Significantly Improved Noise Characteristics

- ESD protection exceeds 2000V
- Power-off disable feature
- Matched Rise and Fall times
- Fully Compatible with TTL Input and Output Logic Levels
- 64 mA Sink Current (Com'l), 32 mA (Mil) 15 mA Source Current (Com'l), 12 mA (Mil)
- Manufactured in 0.7 micron PACE Technology™



#### DESCRIPTION

The 'FCT139T is a dual 1-of-4 decoders which has two independent decoders, each of which accept two binary weighted inputs  $(A_0-A_1)$  and provide four mutual exclusive active LOW outputs  $(\overline{O_0}-\overline{O_3})$ . Each decoder has an active LOW enable (E). When  $\overline{E}$  is HIGH, all outputs are forced HIGH.

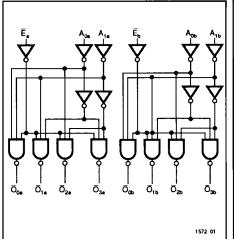
The 'FCT139T is manufactured using PACE Technology™ which is Performance Advanced CMOS Engineered to

use 0.7 micron effective channel lengths giving 400 picoseconds loaded\* internal gate delays. PACE Technology includes two-level metal and epitaxial substrates. In addition to very high performance and very high density, the technology features latch-up protection, single event upset protection, and is supported by a Class 1 environment volume production facility.

\*For a fan-in/fan-out of 4, at 85°C junction temperature and 5.0V.

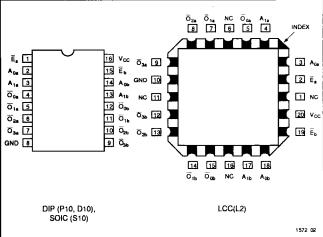


#### **FUNCTIONAL BLOCK DIAGRAM**



# PIN CONFIGURATIONS

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Means Quality, Service and Speed

# **ABSOLUTE MAXIMUM RATINGS<sup>1,2</sup>**

Symbol	Parameter	Value	Unit
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
TA	Ambient Temperature Under Bias	-65 to +135	°C
V <sub>cc</sub>	V <sub>cc</sub> Potential to Ground	-0.5 to +7.0	٧
P <sub>T</sub>	Power Dissipation	0.5	W

1	572	Thi	Ω1

Symbol	Parameter	Value	Unit
OUTPUT	Current Applied to Output	120	mA
Vin	Input Voltage	-0.5 to +7.0	V
V <sub>OUT</sub>	Voltage Applied to Output	-0.5 to +7.0	٧

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#### Notes:

 Operation beyond the limits set forth in the above table may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature range. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V<sub>cc</sub> or ground.

### RECOMMENDED OPERATING CONDITIONS

Free Air Ambient Temperature	Min	Max
Military Commercial	-55°C 0°C	+125°C +70°C
Commercial	1 00	¥70 Q

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Supply Voltage (V <sub>cc</sub> )	Min	Max
Military	+4.5V	+5.5V
Commercial	+4.75V	+5.25V

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# DC ELECTRICAL CHARACTERISTICS (Over recommended operating conditions)

Symbol	Param	eter	Min	Typ¹	Max	Units	V <sub>cc</sub>	Conditions
V <sub>IH</sub>	Input HIGH Voltage		2.0	1		V		
V <sub>IL</sub>	Input LOW Voltage				0.8	V		
V <sub>H</sub>	Hysteresis	· · · · · ·		0.2		V		All inputs
V <sub>IK</sub>	Input Clamp Diode Voltage			-0.7	-1.2	V	MIN	I <sub>IN</sub> = -18mA
V <sub>OH</sub>	Output HIGH Voltage	Military Commercial	2.4 2.4	3.3 3.3		V V	MIN MIN	I <sub>OH</sub> = -12mA I <sub>OH</sub> = -15mA
V <sub>OL</sub>	Output LOW Voltage	Military Commercial Commercial		0.3 0.3 0.3	0.5 0.5 0.5	\ \ \ \ \ \	MIN MIN MIN	I <sub>OL</sub> = 32mA I <sub>OL</sub> = 48mA I <sub>OL</sub> = 64mA
i,	Input HIGH Current				20	μΑ	MAX	$V_{IN} = V_{CC}$
I <sub>tt</sub>	Input HIGH Current				5	μА	MAX	
l <sub>ic</sub>	Input LOW Current				-5	μА	MAX	V <sub>IN</sub> = 0.5V
los	Output Short Circuit Current <sup>2</sup>		-60	-120	-225	mA	MAX	V <sub>OUT</sub> = 0.0V
I <sub>OFF</sub>	Power-off Disable				100	μА	٥V	V <sub>out</sub> = 4.5V
CiN	Input Capacitance <sup>3</sup>		7	6	10	ρF	MAX	All inputs
Cour	Output Capacitance <sup>3</sup>			8	12	pF	MAX	All outputs
Icc	Quiescent Power Supply Cur	rent		0.2	1.5	mA	MAX	V <sub>IN</sub> ≤ 0.2V, V <sub>IN</sub> ≥V <sub>CC</sub> -0.2V

#### Notes:

- 1. Typical limits are at  $V_{cc} = 5.0V$ ,  $T_{A} = +25^{\circ}C$  ambient.
- Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect
- operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, Ios tests should be performed last.
- 3. This parameter is guaranteed but not tested.

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# DC CHARACTERISTICS (Over recommended operating conditions unless otherwise specified.)

Symbol	Parameter	Тур¹	Max	Units	Conditions
Δl <sub>cc</sub>	Quiescent Power Supply Current (TTL inputs HIGH)	0.5	2.0	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 3.4V <sup>2</sup> , f <sub>1</sub> = 0, Outputs Open
I <sub>cco</sub>	Dynamic Power Supply Current <sup>3</sup>	0.15	0.3	mA/ mHz	$V_{CC}$ = MAX, One Input Toggling, 50% Duty Cycle, Outputs Open, $V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC} - 0.2V$
		1.7	4.5	mA	$V_{CC}$ = MAX, $f_1$ = 10 MHz, 50% Duty Cycle, Outputs Open, One Output Toggling, and $V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC} - 0.2V$
I <sub>C</sub>	Total Power Supply Current <sup>4</sup>	2.0	5.5	mA	$ m V_{CC} = MAX, \ f_{\uparrow} = 10 \ MHz, \ 50\% \ Duty Cycle, Outputs Open, \ One Output Toggling and \ V_{IN} = 3.4V \ or \ V_{IN} = GND$
		3.2	7.54	mA	V <sub>CC</sub> = MAX, f <sub>1</sub> = 10 MHz, 50% Duty Cycle, Outputs Open, One Output Toggling on Each Decoder and V <sub>IN</sub> ≤ 0.2V or V <sub>IN</sub> ≥ V <sub>CC</sub> − 0.2V
		3.7	9.54	mA	V <sub>CC</sub> = MAX, f <sub>1</sub> = 10 MHz, 50% Duty Cycle, Outputs Open, One Output Toggling on Each Decoder and V <sub>IN</sub> = 3.4V or V <sub>IN</sub> = GND

### Notes:

1. Typical values are at  $V_{cc}$  = 5.0V, +25°C ambient. 2. Per TTL driven input ( $V_N$  = 3.4V); all other inputs at  $V_{cc}$  or GND.

3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

4. l<sub>c</sub>

 $\begin{array}{lll} & \text{local operations}, \\ & \text{loc} & = \text{louescent} + \text{l}_{\text{NNUTS}} + \text{l}_{\text{DYNUMC}} \\ & \text{loc} & + \Delta \text{loc} \text{D}_{\text{N}} \text{N}_{\text{T}} + \text{loco}(\text{f}_{\text{J}}/2 + \text{f}_{\text{I}}\text{N}_{\text{J}}) \\ & \text{loc} & = \text{Quiescent Current with CMOS input levels} \\ & \Delta \text{loc} & = \text{Power Supply Current for a TTL High Input (V}_{\text{N}} = 3.4\text{V}) \\ & \text{D}_{\text{H}} & = \text{Duty Cycle for TTL Inputs High} \end{array}$ 

N<sub>+</sub> = Number of TTL Inputs at D<sub>u</sub>

I<sub>cco</sub> = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

≈ Clock Frequency for Register Devices (Zero for Non-Register

= Output Frequency

N, = Number of Inputs at f,

All currents are in milliamps and all frequencies are in megahertz.

### TRUTH TABLE

	Inputs		Outputs					
E	A <sub>o</sub>	A,	O <sub>0</sub>	Ō,	Ō,	Ō <sub>3</sub>		
H	Х	Х	Н	Н	Н	Н		
L	L	L	L	н	н	н		
L	H	L	н	L	н	Н		
L	L	Н	н	н	L	н		
L	H	Н	Н	Н	Н	L		

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H = HIGH Voltage Level L = LOW Voltage Level

X = Don't Care

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# **AC CHARACTERISTICS**

		'FCT139T				'FCT1	T139AT			'FCT139CT					
Sym	Parameter	M	L	CON	۸'L	M	L	COI	M'L	M	L	CO	Λ'L	Units	Fig. No.
		Min.¹	Max.	Min.¹	Max.	Min.1	Max.	Min.1	Max.	Min.1	Max.	Min.1	Мах.		
t <sub>PLH</sub>	Prop Delay $A_0$ or $A_1$ to $\overline{O}_n$	1.5	12.0	1.5	9.0	1.5	7.8	1.5	5.9	1.5	6.6	1.5	5.0	ns	1, 5
	Prop Delay $\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	1.5	9.0	1.5	8.0	1.5	7.2	1.5	5.5	1.5	6.2	1.5	4.7	ns	1, 5

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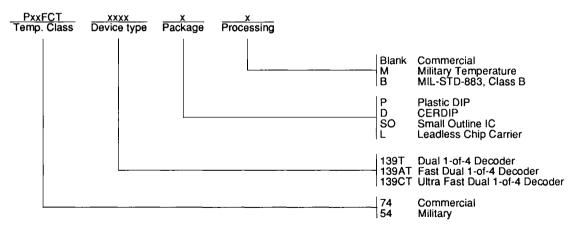
Note:

# **DEFINITION OF FUNCTIONAL TERMS**

Pin Names	Description
A <sub>o</sub> , A <sub>1</sub>	Address Inputs
$\overline{E}_{a}, \overline{E}_{b}$	Enable Inputs (Active LOW)
$\overline{O}_0 - \overline{O}_3$	Outputs (Active LOW)

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## **ORDERING INFORMATION**



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<sup>1.</sup> Minimum limits are guaranteed but not tested on Propagation Delays.